SILICON POWER TRANSISTOR 2SC3569

NPN SILICON TRIPLE DIFFUSED TRANSISTOR FOR HIGH-VOLTAGE HIGH-SPEED SWITCHING

The 2SC3569 is a mold power transistor developed for highvoltage high-speed switching, and is ideal for use in drivers such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

FEATURES

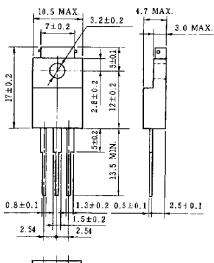
NEC

- Mold package that does not require an insulating board or insulation bushing
- Low collector saturation voltage: VCE(sat) = 1.0 V MAX. (@ 0.7 A)
- Fast switching speed: t_f ≤ 1.0 μs MAX. (@ 0.7 A)
- Wide base reverse-bias SOA: VCEX(SUS) = 450 V MIN. (@ 0.5 A)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	500	V
Collector to emitter voltage	VCEO	400	V
Emitter to base voltage	VEBO	7.0	V
Collector current (DC)	IC(DC)	2.0	А
Collector current (pulse)	IC(pulse)*	4.0	А
Base current (DC)	IB(DC)	1.0	А
Total power dissipation	P⊤ (Tc = 25°C)	15	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

PACKAGE DRAWING (UNIT: mm)





Electrode Connection

1. Base

2. Collector

3. Emitter

* PW \leq 300 μ s, duty cycle \leq 10%

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

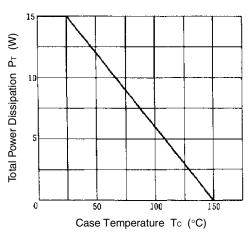
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = 0.5 A, Iв1 = 0.1 A, L = 1 mH	400			V
Collector to emitter voltage	VCEX(SUS)1	Ic = 0.5 A, I _{B1} = $-I_{B2}$ = 0.1 A, L = 180 μ H, clamped	450			V
Collector to emitter voltage	VCEX(SUS)2	Ic = 1.0 A, I _{B1} = 0.2 A, $-I_{B2}$ = 0.1 A, L = 180 μ H, clamped				V
Collector cutoff current	Ісво	$V_{CB} = 400 \text{ V}, \text{ I}_{E} = 0$			10	μA
Collector cutoff current	ICER	V _{CE} = 400 V, R _{BE} = 51 Ω, Ta = 125°C			1.0	mA
Collector cutoff current	ICEX1	$V_{\text{CE}} = 400 \text{ V}, \text{ V}_{\text{BE(OFF)}} = -1.5 \text{ V}$			10	μΑ
Collector cutoff current	ICEX2	$V_{CE} = 400 \text{ V}, \text{ V}_{BE(OFF)} = -1.5 \text{ V},$ Ta = 125°C			1.0	mA
Emitter cutoff current	Іево	V _{EB} = 5.0 V, Ic = 0			10	μA
DC current gain	hfe1*	Vce = 5.0 V, Ic = 0.2 A	20		80	
DC current gain	hfe2*	Vce = 5.0 V, Ic = 0.5 A	10			
Collector saturation voltage	V _{CE(sat)} *	Ic = 0.7 A, I _B = 0.14 A			1.0	V
Base saturation voltage	V _{BE(sat)} *	Ic = 0.7 A, Iв = 0.14 A			1.2	V
Turn-on time	ton	$I_{C} = 0.7 \text{ A}, \text{ R}_{L} = 214 \Omega,$			1.0	μs
Storage time	tstg	I _{B1} = −I _{B2} = 0.14 A, V _{CC} ≅ 150 V Refer to the test circuit.			2.5	μs
Fall time	tr				1.0	μs

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

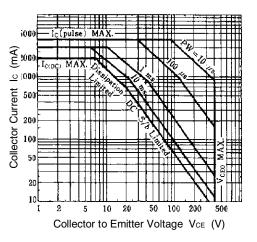
hFE CLASSIFICATION

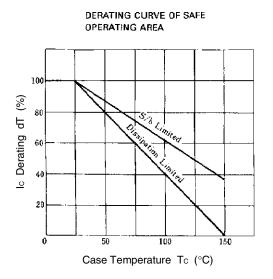
Marking	М	L	К
HFE1	20 to 40	30 to 60	40 to 80

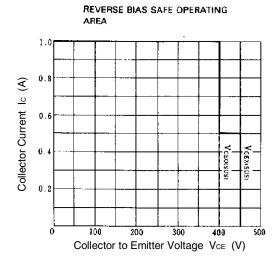
TYPICAL CHARACTERISTICS (Ta = 25°C)

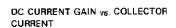


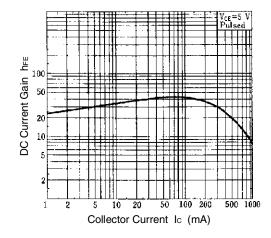
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE FORWARD BIAS SAFE OPERATING AREA



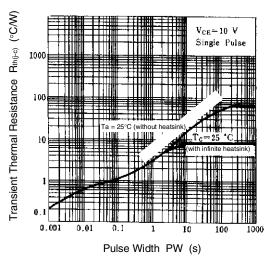




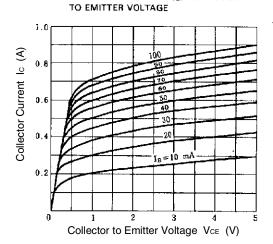




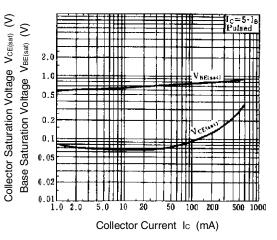
TRANSIENT THERMAL RESISTANCE

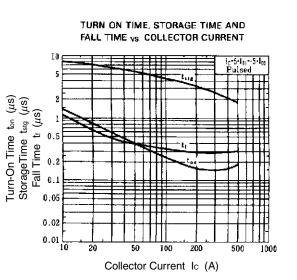


COLLECTOR CURRENT VS. COLLECTOR

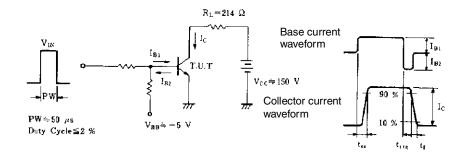


BASE AND COLLECTOR SATURATION VOLTAGE VS. COLLECTOR CURRENT





SWITCHING TIME (ton, tstg, tr) TEST CIRCUIT



[MEMO]

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